

October 1987 Revised January 1999

# CD4071BC • CD4081BC Quad 2-Input OR Buffered B Series Gate • Quad 2-Input AND Buffered B Series Gate

### **General Description**

The CD4071BC and CD4081BC quad gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.

All inputs protected against static discharge with diodes to  $\rm V_{DD}$  and  $\rm V_{SS}.$ 

### **Features**

- Low power TTL compatibility:

  Fan out of 2 driving 74L or 1 driving 74LS
- 5V-10V-15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 µA at 15V over full temperature range

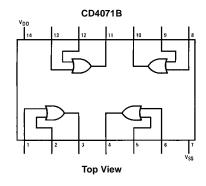
### **Ordering Code:**

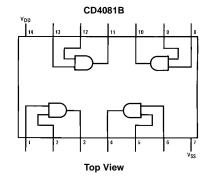
Order Number	Package Number	Package Description
CD4071BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
CD4071BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
CD4081BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
CD4081BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices are also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

### **Connection Diagrams**

### Pin Assignments for DIP and SOIC







## **Schematic Diagrams** CD4071B $^{1}\!/_{_{\!4}}$ of device shown $\mathsf{J}=\mathsf{A}+\mathsf{B}$ Logical "1" = HIGH Logical "0" = LOW \*All inputs protected by standard CMOS protection circuit. CD4081B $^{1}\!/_{_{\!\!4}}$ of device shown $\mathsf{J}=\mathsf{A}\bullet\mathsf{B}$ Logical "1" = HIGH Logical "0" = LOW All inputs protected by standard CMOS protection circuit.

### **Absolute Maximum Ratings**(Note 1)

(Note 2)

Voltage at Any Pin  $$-0.5\mathrm{V}$ to \ \mathrm{V}_{\mathrm{DD}}\,+0.5\mathrm{V}$$ 

Power Dissipation (P<sub>D</sub>)

 $\begin{array}{ccc} \text{Dual-In-Line} & 700 \text{ mW} \\ \text{Small Outline} & 500 \text{ mW} \\ \text{V}_{\text{DD}} \text{ Range} & -0.5 \text{ V}_{\text{DC}} \text{ to +18 V}_{\text{DC}} \end{array}$ 

-65°C to +150°C

Storage Temperature (T<sub>S</sub>)

Lead Temperature (T<sub>L</sub>)

(Soldering, 10 seconds) 260°C

### Recommended Operating Conditions

Operating Range ( $V_{DD}$ ) 3  $V_{DC}$  to 15  $V_{DC}$ 

Operating Temperature Range (T<sub>A</sub>)

CD4071BC, CD4081BC -40°C to +85°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: All voltages measured with respect to  $V_{\mbox{SS}}$  unless otherwise specified

### DC Electrical Characteristics (Note 2)

CD4071BC/CD4081BC

Symbol	Parameter	Conditions	-40°C		+25°C			+85°C		Units
			Min	Max	Min	Тур	Max	Min	Max	Units
I <sub>DD</sub>	Quiescent Device	$V_{DD} = 5V$		1		0.004	1		7.5	μΑ
	Current	$V_{DD} = 10V$		2		0.005	2		15	μΑ
		$V_{DD} = 15V$		4		0.006	4		30	μΑ
V <sub>OL</sub>	LOW Level	$V_{DD} = 5V$		0.05		0	0.05		0.05	V
	Output Voltage	$V_{DD} = 10V \hspace{1cm}  I_O  < 1 \hspace{1cm} \mu A$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	V
V <sub>OH</sub>	HIGH Level	$V_{DD} = 5V$	4.95		4.95	5		4.95		V
	Output Voltage	$V_{DD} = 10V \qquad   I_O  < 1 \; \mu A$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		V
V <sub>IL</sub>	LOW Level	$V_{DD} = 5V, V_{O} = 0.5V$		1.5		2	1.5		1.5	V
	Input Voltage	$V_{DD} = 10V, V_{O} = 1.0V$		3.0		4	3.0		3.0	V
		$V_{DD} = 15V, V_{O} = 1.5V$		4.0		6	4.0		4.0	V
V <sub>IH</sub>	HIGH Level	$V_{DD} = 5V, V_{O} = 4.5V$	3.5		3.5	3		3.5		V
	Input Voltage	$V_{DD} = 10V, V_{O} = 9.0V$	7.0		7.0	6		7.0		V
		$V_{DD} = 15V, V_{O} = 13.5V$	11.0		11.0	9		11.0		V
I <sub>OL</sub>	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.52		0.44	0.88		0.36		mA
	Current	$V_{DD} = 10V, V_{O} = 0.5V$	1.3		1.1	2.25		0.9		mA
	(Note 3)	$V_{DD} = 15V, V_{O} = 1.5V$	3.6		3.0	8.8		2.4		mA
l <sub>OH</sub>	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.52		-0.44	-0.88		-0.36		mA
	Current	$V_{DD} = 10V, V_{O} = 9.5V$	-1.3		-1.1	-2.25		-0.9		mA
	(Note 3)	$V_{DD} = 15V, V_{O} = 13.5V$	-3.6		-3.0	-8.8		-2.4		mA
I <sub>IN</sub>	Input Current	V <sub>DD</sub> = 15V, V <sub>IN</sub> = 0V		-0.30		-10 <sup>-5</sup>	-0.30		-1.0	μА
		$V_{DD} = 15V, V_{IN} = 15V$		0.30		10 <sup>-5</sup>	0.30		1.0	μΑ

Note 3:  $I_{\mbox{\scriptsize OH}}$  and  $I_{\mbox{\scriptsize OL}}$  are tested one output at a time.

### **AC Electrical Characteristics** (Note 4)

CD4071BC T  $_{A}$  = 25  $^{\circ}$  C, Input  $t_{r}; t_{f}$  = 20 ns, C  $_{L}$  = 50 pF, R  $_{L}$  = 200 k $\Omega$  , Typical temperature coefficient is 0.3%/ $^{\circ}$  C

Symbol	Parameter	Conditions	Тур	Max	Units
t <sub>PHL</sub>	Propagation Delay Time,	$V_{DD} = 5V$	100	250	ns
	HIGH-to-LOW Level	$V_{DD} = 10V$	40	100	ns
		$V_{DD} = 15V$	30	70	ns
t <sub>PLH</sub>	Propagation Delay Time,	$V_{DD} = 5V$	90	250	ns
	LOW-to-HIGH Level	$V_{DD} = 10V$	40	100	ns
		$V_{DD} = 15V$	30	70	ns
t <sub>THL</sub> , t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$	90	200	ns
		$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	40	80	ns
C <sub>IN</sub>	Average Input Capacitance	Any Input	5	7.5	pF
C <sub>PD</sub>	Power Dissipation Capacity	Any Gate	18		pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

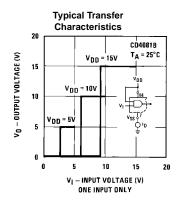
### **AC Electrical Characteristics** (Note 5)

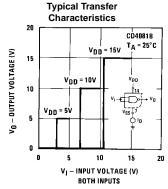
CD4081BC T  $_{A}$  = 25°C, Input t  $_{r}$ ; t  $_{f}$  = 20 ns, C  $_{L}$  = 50 pF, R  $_{L}$  = 200 k  $\Omega$  , Typical temperature coefficient is 0.3%/°C

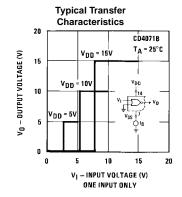
Symbol	Parameter	Conditions	Тур	Max	Units
t <sub>PHL</sub>	Propagation Delay Time,	$V_{DD} = 5V$	100	250	ns
	HIGH-to-LOW Level	$V_{DD} = 10V$	40	100	ns
		$V_{DD} = 15V$	30	70	ns
t <sub>PLH</sub>	Propagation Delay Time,	$V_{DD} = 5V$	120	250	ns
	LOW-to-HIGH Level	$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	35	70	ns
t <sub>THL</sub> , t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$	90	200	ns
		$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	40	80	ns
C <sub>IN</sub>	Average Input Capacitance	Any Input	5	7.5	pF
C <sub>PD</sub>	Power Dissipation Capacity	Any Gate	18		pF

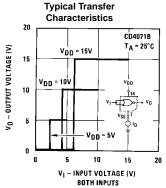
Note 5: AC Parameters are guaranteed by DC correlated testing.

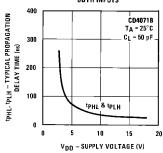
### **Typical Performance Characteristics**

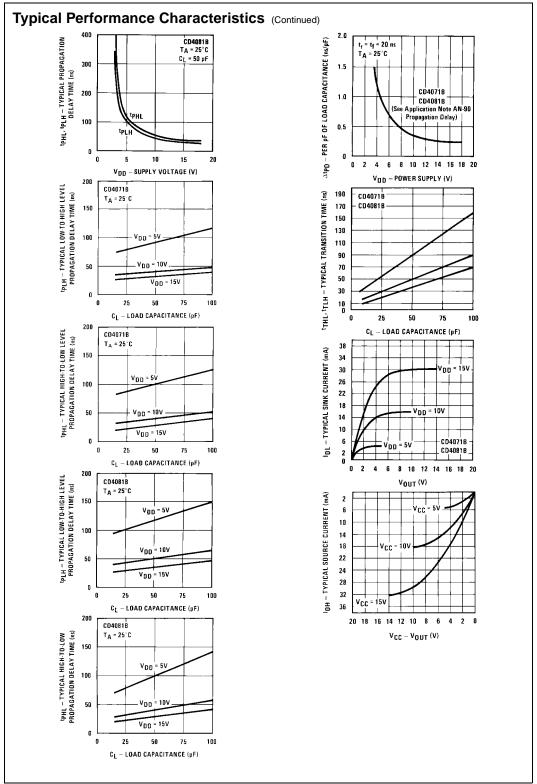


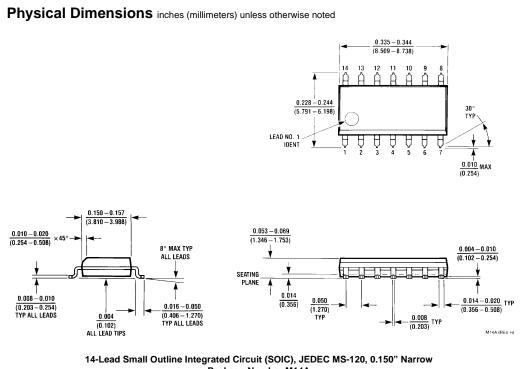




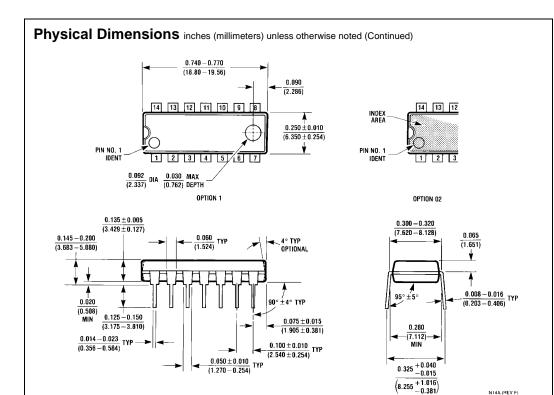








Package Number M14A



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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